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Inclosure Material:

Metal

**Overall Length:** 

1.453 inches

#### **Overall Diameter:**

0.667 inches

#### **Mounting Facility Quantity:**

1

#### Electrode Internally-electrically Connected To Case:

Cathode

#### **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.667 inches and 0.687 inches

#### **Thread Size:**

0.250 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

62.0 regulator voltage

#### Voltage Tolerance In Percent:

-5.0 to 5.0

### Current Rating Per Characteristic:

200.00 milliamperes voltage regulator diode current and 770.00 milliamperes dc current in reverse breakdown region

#### **Power Rating Per Characteristic:**

50.0 watts total power dissipation

#### Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius case

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Thread Series Designator:**

Unf

Terminal Type And Quantity: 1 threaded stud and 1 tab, solder lug Specification Data: 81349-mil-s-19500/358 government specification Shelf Life:

## N/a

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- Unit Of Measure:
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Demilitarization:

No

Fiig:

A110a0

